A high mobility two-dimensional electron gas at the CaZrO3/SrTiO3 heterointerface

Chen, Yunzhong; Trier, Felix; Christensen, Dennis Valbjørn; Linderøth, Søren; Pryds, Nini

Publication date: 2016

Document Version
Peer reviewed version

Link back to DTU Orbit

Citation (APA):
A high mobility two-dimensional electron gas at the CaZrO$_3$/SrTiO$_3$ heterointerface

Y.Z. Chen$^*$, F. Trier, D. V. Christensen, S. Linderoth, and Nini Pryds
Department of Energy Conversion and Storage, Technical University of Denmark, Roskilde, Denmark
$^*$ yuc@dtu.dk

The discovery of two-dimensional electron gases (2DEGs) in SrTiO$_3$-based heterostructures provides new opportunities for nanoelectronics$^{1,2}$. Herein, we create a new type of oxide 2DEG by the epitaxial-strain-induced polarization at an otherwise nonpolar perovskite-type interface of CaZrO$_3$/SrTiO$_3$. Remarkably, this heterointerface is atomically sharp, and exhibits a high electron mobility exceeding 60,000 cm$^2$V$^{-1}$s$^{-1}$ at low temperatures. The 2DEG carrier density exhibits a critical dependence on the film thickness, in good agreement with the polarization induced 2DEG scheme.

Figure 1. Atomically-flat epitaxially grown perovskite-type interface of CaZrO$_3$/SrTiO$_3$ determined by STEM-EELS.

Reference: